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# Schottky Barrier Rectifier

Qualified per MIL-PRF-19500/553

#### DESCRIPTION

This schottky barrier diode provides low forward voltage and offers military grade qualifications for high-reliability applications. This rugged DO-203AA rectifier is applicable for freewheeling diodes, rectification in high-frequency, low-voltage inverters, and for polarity protection.

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FEATURES

- Internal solder bond construction.
- Hermetically sealed (welded).
- 600 Amps surge rating.
- JAN, JANTX, JANTXV and JANS qualifications are available per MIL-PRF-19500/553.
- RoHS compliant devices available by adding "e3" suffix (commercial grade only).

#### **APPLICATIONS / BENEFITS**

- Metal and glass construction.
- Reverse energy tested.
- Fast recovery.

#### **MAXIMUM RATINGS** @ $T_A = +25$ °C unless otherwise stated

| Parameters/Test Conditions   | Symbol                                   | Value       | Unit |
|--|--|-------------|------|
| Junction and Storage Temperature   | $T_{\rm J}$ and $T_{\rm STG}$            | -55 to +175 | °C   |
| Thermal Resistance Junction-to-Case  | R <sub>eJC</sub>                         | 2.0         | °C/W |
| Reverse Voltage, Repetitive Peak and Working Peak Reverse Voltage <sup>(1)</sup>         | V <sub>RRM</sub> and<br>V <sub>RWM</sub> | 45          | V    |
| Reverse Voltage, Nonrepetitive Peak  | V <sub>RSM</sub>                         | 54          | V    |
| Reverse Voltage <sup>(1)</sup>   | V <sub>R</sub>                           | 45          | V    |
| Forward Surge Current @ 8.3 ms half-sine wave  | I <sub>FSM</sub>                         | 600         | Α    |
| Average Forward Current 50% duty cycle square wave<br>@ $T_{C}$ = +125 °C <sup>(2)</sup> | I <sub>FM</sub>                          | 25          | A    |
| Average Rectified Output Current @ $T_c$ = +125 °C <sup>(3)</sup>                        | Ι <sub>ο</sub>                           | 22.5        | Α    |
| Solder Pad Temperature @ 10 s  |  | 260         | °C   |

#### <u>Qualified Levels</u>: JAN, JANTX, JANTXV and JANS



### DO-203AA (DO-4) Package

#### MSC – Lawrence

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- **NOTES:** 1. Full rated  $V_{RRM}$  and  $V_{RWM}$  with 50% duty cycle is applicable over the range of  $T_C = -55$  °C to +165 °C for I<sub>FM</sub> = 0. Full rated continuous  $V_R$  (dc) is applicable over the temperature range of  $T_C = -55$  to +155 °C. When  $V_R = 45$  V and  $T_C = +155$  °C, then  $T_J = 175$  °C.
  - 2. Average current with a 50 percent duty cycle square wave including reverse amplitude equal to the magnitude of full rated V<sub>RWM</sub>. Derate linearly at 0.625 A/°C for T<sub>C</sub> > +125 °C.
  - Average current with an applied half-sine wave peak voltage value equal to the magnitude of full rated V<sub>RWM</sub>. For temperature-current derating curves, see <u>Figure 4</u>.



#### **MECHANICAL and PACKAGING**

- CASE: Industry standard DO-4, (DO-203AA), 7/16" hex, stud with 10-32 threads, welded, hermetically sealed metal and glass.
- TERMINALS: Tin-lead plated or RoHS compliant matte-tin plating (commercial grade only) on nickel.
- POLARITY: Cathode to stud.
- MOUNTING HARDWARE: Nut, flat steel washer and lock washer available upon request.
- WEIGHT: Approximately 7.5 grams.
- See <u>Package Dimensions</u> on last page.

#### PART NOMENCLATURE



| SYMBOLS & DEFINITIONS |  |  |  |  |  |
|-----------------------|--|--|--|--|--|
| Symbol                | Definition   |  |  |  |  |
| f                     | Frequency  |  |  |  |  |
| I <sub>FM</sub>       | Forward Current: The current flowing from the external circuit into the anode terminal. Also see first page ratings and test conditions for I <sub>FM</sub> with 50% duty cycle square wave. |  |  |  |  |
| I <sub>FSM</sub>      | Surge Peak Forward Current: The forward current including all nonrepetitive transient currents but excluding all repetitive transients (ref JESD282-B).                                      |  |  |  |  |
| Ι <sub>Ο</sub>        | Average Rectified Forward Current: The output current averaged over a full cycle with a 50 Hz or 60 Hz sine-wave input and a 180 degree conduction angle.                                    |  |  |  |  |
| V <sub>FM</sub>       | Maximum Forward Voltage  |  |  |  |  |
| V <sub>R</sub>        | Reverse Voltage: A positive dc cathode-anode voltage below the breakdown region.   |  |  |  |  |
| V <sub>RRM</sub>      | Repetitive Peak Reverse Voltage: The peak reverse voltage including all repetitive transient voltages but excluding all non-repetitive transient voltages.                                   |  |  |  |  |
| V <sub>RSM</sub>      | Non-Repetitive Peak Inverse Voltage: The peak reverse voltage including all non-repetitive transient voltages but excluding all repetitive transient voltages.                               |  |  |  |  |
| V <sub>RWM</sub>      | Working Peak Reverse Voltage: The peak voltage excluding all transient voltages (ref JESD282-B). Also sometimes known historically as PIV.   |  |  |  |  |



#### ELECTRICAL CHARACTERISTICS

| Parameters / Test Conditions   | Symbol          | Min. | Max.                    | Тур. | Unit |
|--|-----------------|------|-------------------------|------|------|
| Forward Voltage<br>$I_{FM} = 50 \text{ A}, T_C = 25 \text{ °C }^*$<br>$I_{FM} = 5 \text{ A}, T_C = 25 \text{ °C }^*$   | V <sub>FM</sub> |      | 0.68<br>0.50            |      | V    |
| Reverse Current Leakage<br>$V_{RM} = 45 \text{ V}, \text{ T}_{J} = 25 \text{ °C}$<br>$V_{RM} = 45 \text{ V}, \text{ T}_{J} = 175 \text{ °C} \text{ *}$<br>$V_{RM} = 45 \text{ V}, \text{ T}_{J} = 125 \text{ °C} \text{ *}$<br>$V_{RM} = 45 \text{ V}, \text{ T}_{C} = -55 \text{ °C} \text{ *}$ | I <sub>RM</sub> |      | 1.5<br>220<br>40<br>1.5 |      | mA   |
| Junction Capacitance $V_R = 5 V$ , f = 1 MHz, 100 KHz $\leq$ f $\leq$ 1 MHz  | CJ              |      | 2000                    |      | pF   |

\*Pulse test: pulse width 300  $\mu sec,$  duty cycle 2%



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Typical Reverse Characteristics



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FIGURE 3 Typical Junction Capacitance



 $\frac{\text{Temperature} - \text{Current Derating Curve}}{\text{(Derate design curve constrained by the maximum rated junction temperature (TJ ≤ 175C) and current rating specified.)}$ 



#### **PACKAGE DIMENSIONS**



|                 | Dimensions |       |             |       |       |
|-----------------|------------|-------|-------------|-------|-------|
| Ltr             | Inch       |       | Millimeters |       | Notes |
|                 | Min        | Max   | Min         | Max   |       |
| С               |            | .250  |             | 6.35  | 5     |
| C <sub>1</sub>  | 0.018      | 0.65  | 0.46        | 1.65  | 5     |
| CD              | 0.265      | 0.424 | 6.73        | 10.77 | 6     |
| СН              | 0.300      | 0.405 | 7.62        | 10.29 |       |
| HF              | 0.403      | 0.437 | 10.24       | 11.1  | 6     |
| HT <sub>1</sub> | 0.075      | 0.175 | 1.91        | 4.45  | 7     |
| HT <sub>2</sub> | 0.060      | -     | 1.53        | -     | 7     |
| OAH             | 0.600      | 0.800 | 15.24       | 20.32 |       |
| SD              |            |       |             |       | 2     |
| SL              | 0.422      | 0.453 | 10.72       | 11.51 |       |
| SU              |            | 0.078 |             | 1.98  | 8     |
| UD              | 0.163      | 0.189 | 4.14        | 4.80  |       |
| ΦT              | 0.060      | 0.095 | 1.52        | 2.41  |       |

#### NOTES:

- 1. Dimensions are in inches. Millimeters are given for information only.
- 2. See "mechanical and packaging" for the polarity of the terminals.
- 3. Threads shall be 10–32 UNF–2A in accordance with FED–STD–H28. Maximum pitch diameter (SD) of plated threads shall be basic pitch diameter 0.1697 inch (4.31 mm).
- Device shall not be damaged by a torque of 15 inch-pounds applied to a 10-32 UNF-2B nut assembled on thread.
- 5. The angular orientation and peripheral configuration of terminal 1 is undefined, however, the major surfaces over dimension C and C1 shall be flat.
- 6. Dimension CD cannot exceed dimension HF.
- 7. A chamfer or undercut on one or both ends of the hex portion is optional; minimum base diameter at seating plane 0.403 inch (10.24 mm).
- 8. Length of incomplete or undercut threads UD.
- 9. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

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